2SC5249

Silicon NPN Triple Diffused Planar Transistor (High Voltage Switching Transistor)

Application: Switching Regulator and General Purpose

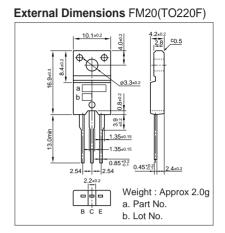
■Absolute maximum ratings (Ta=25°C) Symbol Ratings Unit 600 VCEO 600 ٧ Vево V 3(Pulse6) Ic Α lв 1.5 Α Рc 35(Tc=25°C) W 150

-55 to +150

Τj

Tstg

■Electrical Cl	naracteristics	(Ta=25°C)			
Symbol	Conditions	Ratings	Unit		
Ісво	Vcb=600V	100max	μΑ		
Ієво	VEB=7V	100max	μΑ		
V(BR)CEO	Ic=10mA	600min	V		
hfe	Vce=4V, Ic=1A	20 to 40			
Vce(sat)	Ic=1A, IB=0.2A	0.5max	V		
VBE(sat)	Ic=1A, IB=0.2A	1.2max	V		
fт	Vce=12V, Ie=-0.3A	6typ	MHz		
Сов	VcB=10V, f=1MHz	50typ	pF		



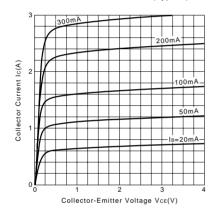
■Typical Switching Characteristics (Common Emitter)

°C

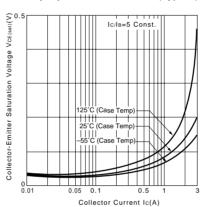
°C

			•		•				
Vcc (V)	Rι (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	I _{B1} (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
200	200	1	10	-5	0.1	-0.1	1.0max	19max	1.0max

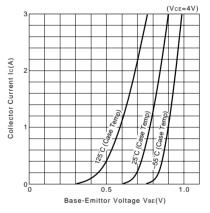
Ic-VcE Characteristics (Typical)



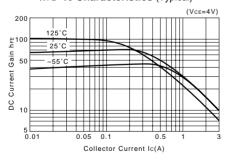
VcE(sat)-Ic Characteristics (Typical)



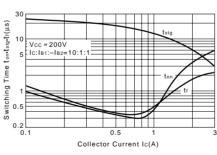
Ic-VBE Temperature Characteristics (Typical)



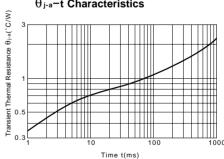
hfe-Ic Characteristics (Typical)



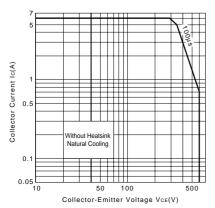
ton•tstg•tf-Ic Characteristics (Typical)



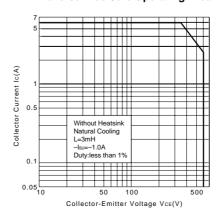
θ_{j-a}-t Characteristics



Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating

